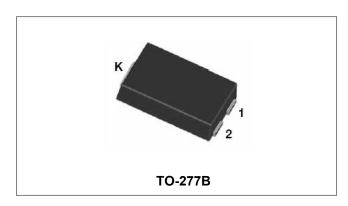






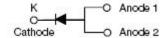
ST20100S SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Trench MOS Schottky technology
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _L =125°C, rectangular wave form	20	Α
Peak One Cycle Non-Repetitive Surge Current	IFSM	8.3ms, Half Sine pulse, T _J = 25 °C	270	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 10A, Pulse, T _J = 25 °C @ 20A, Pulse, T _J = 25 °C	0.58 0.74	- 0.78	V
	V_{F2}	@ 10A, Pulse, T _J = 125 °C @ 20A, Pulse, T _J = 125 °C	0.53 0.64	- 0.68	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	0.02	0.1	mA
Reverse Current*	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	13	35	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	950	-	pF

^{*} Pulse width < 300 μ s, duty cycle < 2%

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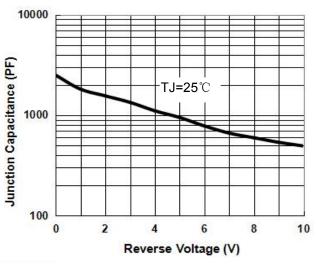


Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient (NOTE1)	$R_{ heta JA}$	DC operation	75	°C/W
Typical Thermal Resistance Junction to Lead (NOTE1)	$R_{ heta JL}$	DC operation	4	°C/W
Approximate Weight	wt	-	0.08	g

NOTE: 1. Units mounted on P.C.B., 0.5 x 0.5" (30 x 30mm) copper pads.

Ratings and Characteristics Curves



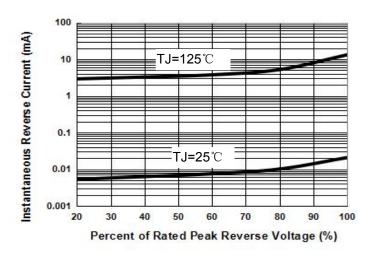


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

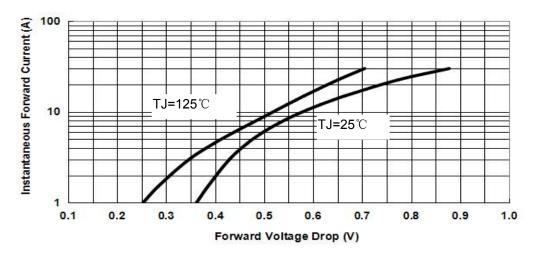


Fig.3-Typical Instantaneous Forward Voltage Characteristics

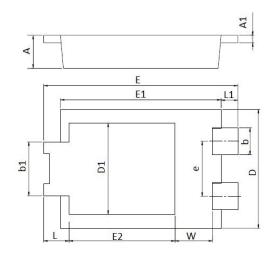
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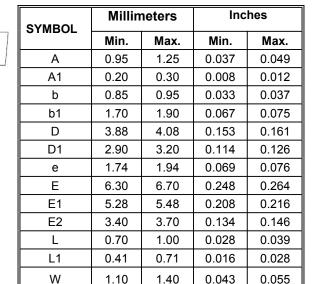




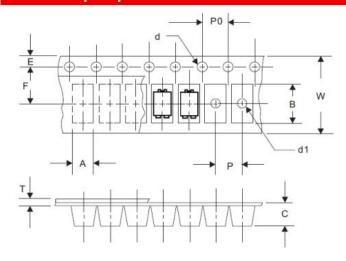


Mechanical Dimensions TO-277B





Carrier Tape Specification TO-277B



SYMBOL	Millimeters		
	Min.	Max.	
Α	4.28	4.48	
В	6.80	7.10	
С	1.30	1.50	
d	1.40	1.60	
d1	-	1.50	
E	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
Т	0.24	0.44	
W	11.70	12.30	

Ordering Information

Device	Package	Shipping
ST20100S	TO-277B(Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

T = Device Type 20 = Forward Current (20A) 100 = Reverse Voltage (100V) S = Package type YY = Year

YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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